

# IEC TS 62607-6-19

Edition 1.0 2021-10

# TECHNICAL SPECIFICATION



Nanomanufacturing - Key control characteristics - VIE W Part 6-19: Graphene-based material - Elemental composition: CS analyser, ONH analyser

> <u>IEC TS 62607-6-19:2021</u> https://standards.iteh.ai/catalog/standards/sist/2b0e1a7f-e389-4fea-9722-4cd8e4f6f681/iec-ts-62607-6-19-2021





#### THIS PUBLICATION IS COPYRIGHT PROTECTED Copyright © 2021 IEC, Geneva, Switzerland

All rights reserved. Unless otherwise specified, no part of this publication may be reproduced or utilized in any form or by any means, electronic or mechanical, including photocopying and microfilm, without permission in writing from either IEC or IEC's member National Committee in the country of the requester. If you have any questions about IEC copyright or have an enquiry about obtaining additional rights to this publication, please contact the address below or your local IEC member National Committee for further information.

IEC Central Office 3, rue de Varembé CH-1211 Geneva 20 Switzerland

Tel.: +41 22 919 02 11 info@iec.ch

#### www.iec.ch

#### About the IEC

The International Electrotechnical Commission (IEC) is the leading global organization that prepares and publishes International Standards for all electrical, electronic and related technologies.

The technical content of IEC publications is kept under constant review by the IEC. Please make sure that you have the latest edition, a corrigendum or an amendment might have been published.

#### IEC publications search - webstore.iec.ch/advsearchform

The advanced search enables to find IEC publications by a variety of criteria (reference number, text, technical committee, ...). It also gives information on projects, replaced and withdrawn publications.

**IEC Just Published - webstore.iec.ch/justpublished**Stay up to date on all new IEC publications. Just Published details all new publications released. Available online and once a month by email.

#### IEC Customer Service Centre - webstore iec ch/csc If you wish to give us your feedback on this publication or

need further assistance, please contact the Customer Service Centre: sales@iec.ch.

IEC TS 62607-6-19:2021

#### IEC online collection - oc.iec.ch

Discover our powerful search engine and read freely all the publications previews. With a subscription you will always have access to up to date content tailored to your needs.

#### Electropedia - www.electropedia.org

The world's leading online dictionary on electrotechnology, containing more than 22 000 terminological entries in English and French, with equivalent terms in 18 additional languages. Also known as the International Electrotechnical Vocabulary (IEV) online. ds.iteh.ai

https://standards.iteh.ai/catalog/standards/sist/2b0e1a7f-e389-4fea-9722 4cd8e4f6f681/iec-ts-62607-6-19-2021



## IEC TS 62607-6-19

Edition 1.0 2021-10

# TECHNICAL SPECIFICATION



Nanomanufacturing • Key control characteristics • VIEW
Part 6-19: Graphene-based material • Elemental composition: CS analyser,
ONH analyser

<u>IEC TS 62607-6-19:2021</u> https://standards.iteh.ai/catalog/standards/sist/2b0e1a7f-e389-4fea-9722-4cd8e4f6f681/iec-ts-62607-6-19-2021

INTERNATIONAL ELECTROTECHNICAL COMMISSION

ICS 07.120 ISBN 978-2-8322-1033-0

Warning! Make sure that you obtained this publication from an authorized distributor.

#### CONTENTS

FOREW	ORD	4
INTROD	UCTION	6
1 Sco	pe	7
2 Nor	mative references	7
3 Teri	ms and definitions	7
3.1	General terms	7
3.2	Key control characteristics measured according to this document	
3.3	Terms related to the measurement method	
4 Ger	eral	10
4.1	Measurement principle	10
4.2	Sample preparation method	11
4.3	Description of measurement equipment / apparatus	11
4.4	Supporting materials	
4.5	Ambient conditions during measurement	
5 Mea	surement procedure	
5.1	Calibration of measurement equipment	
5.2	Detailed protocol of the measurement procedure	
5.3	Measurement accuracy	13
6 Data	a analysis / interpretation of results	13
7 Res	ults to be reported (standards.iteh.ai)	
7.1	General  Product / sample identification https://standards.iteh.avcatalog/standards/sist/2b0e1a7f-e389-4tea-9722-	13
7.2	Product / sample identification 13 02007-0-19.2021 https://standards.iteh.a/catalog/standards/sist/2b0e1a7f-e389-4tea-9722-	13
7.3	1 est conditions4vd8e4f6f681/iev-ts-62607-6-19-2021	13
7.4	Measurement specific information	
7.5	Test results	
	(informative) Test report	
A.1	Recommended format of the test report	14
	(informative) Case study: Comparative results between CS/ONH analyser EA	16
B.1	Measurement sample	
B.1	Measurement equipment	
B.3	Measurement results	
B.3.		
B.3.		
B.3.	· · · · · · · · · · · · · · · · · · ·	
B.3.		
B.3.	5 Measuring samples with high S content (mass fraction (%)):	18
B.3.	6 Measuring samples with low O content (mass fraction (%)):	18
B.3.	7 Measuring samples with high O content (mass fraction (%)):	19
B.3.	8 Measuring samples with low N content (mass fraction (%)):	20
B.3.	9 Measuring samples with high N content (mass fraction (%)):	20
Bibliogra	phy	23
Figure B	.1 – Measurement results of samples with low C content	16
Figure B	.2 – Measurement results of samples with high C content	17

Figure B.4 – Measurement results of samples with high S content	Figure B.3 – Measurement results of samples with low S content	18
Figure B.6 – Measurement results of samples with high O content	Figure B.4 – Measurement results of samples with high S content	18
Figure B.7 – Measurement results of samples with low N content	Figure B.5 – Measurement results of samples with low O content	19
Figure B.8 – Measurement results of samples with high N content	Figure B.6 – Measurement results of samples with high O content	20
Figure B.9 – A summary of SD of all measurements	Figure B.7 – Measurement results of samples with low N content	20
Table A.1 – Product identification	Figure B.8 – Measurement results of samples with high N content	21
Table A.2 – General material description14Table A.3 – Information relating to test15Table A.4 – Measurement results15Table B.1 – Measurement results of samples with low C content16Table B.2 – Measurement results of samples with high C content17Table B.3 – Measurement results of samples with low S content17Table B.4 – Measurement results of samples with high S content18Table B.5 – Measurement results of samples with low O content19Table B.6 – Measurement results of samples with high O content19Table B.7 – Measurement results of samples with low N content20	Figure B.9 – A summary of SD of all measurements	22
Table A.3 – Information relating to test15Table A.4 – Measurement results15Table B.1 – Measurement results of samples with low C content16Table B.2 – Measurement results of samples with high C content17Table B.3 – Measurement results of samples with low S content17Table B.4 – Measurement results of samples with high S content18Table B.5 – Measurement results of samples with low O content19Table B.6 – Measurement results of samples with high O content19Table B.7 – Measurement results of samples with low N content20	Table A.1 – Product identification	14
Table A.4 – Measurement results	·	
Table B.1 – Measurement results of samples with low C content16Table B.2 – Measurement results of samples with high C content17Table B.3 – Measurement results of samples with low S content17Table B.4 – Measurement results of samples with high S content18Table B.5 – Measurement results of samples with low O content19Table B.6 – Measurement results of samples with high O content19Table B.7 – Measurement results of samples with low N content20		
Table B.2 – Measurement results of samples with high C content17Table B.3 – Measurement results of samples with low S content17Table B.4 – Measurement results of samples with high S content18Table B.5 – Measurement results of samples with low O content19Table B.6 – Measurement results of samples with high O content19Table B.7 – Measurement results of samples with low N content20	Table A.4 – Measurement results	15
Table B.3 – Measurement results of samples with low S content       17         Table B.4 – Measurement results of samples with high S content       18         Table B.5 – Measurement results of samples with low O content       19         Table B.6 – Measurement results of samples with high O content       19         Table B.7 – Measurement results of samples with low N content       20	Table B.1 – Measurement results of samples with low C content	16
Table B.4 – Measurement results of samples with high S content	Table B.2 – Measurement results of samples with high C content	17
Table B.5 – Measurement results of samples with low O content	Table B.3 – Measurement results of samples with low S content	17
Table B.6 – Measurement results of samples with high O content	Table B.4 – Measurement results of samples with high S content	18
	Table B.5 – Measurement results of samples with low O content	19
	Table B.6 – Measurement results of samples with high O content	19
Table B.8 – Measurement results of samples with high N content21	Table B.7 – Measurement results of samples with low N content	20
	Table B.8 – Measurement results of samples with high N content	21

IEC TS 62607-6-19:2021 https://standards.iteh.ai/catalog/standards/sist/2b0e1a7f-e389-4fea-9722-4cd8e4f6f681/iec-ts-62607-6-19-2021

#### INTERNATIONAL ELECTROTECHNICAL COMMISSION

#### NANOMANUFACTURING - KEY CONTROL CHARACTERISTICS -

# Part 6-19: Graphene-based material – Elemental composition: CS analyser, ONH analyser

#### **FOREWORD**

- 1) The International Electrotechnical Commission (IEC) is a worldwide organization for standardization comprising all national electrotechnical committees (IEC National Committees). The object of IEC is to promote international co-operation on all questions concerning standardization in the electrical and electronic fields. To this end and in addition to other activities, IEC publishes International Standards, Technical Specifications, Technical Reports, Publicly Available Specifications (PAS) and Guides (hereafter referred to as "IEC Publication(s)"). Their preparation is entrusted to technical committees; any IEC National Committee interested in the subject dealt with may participate in this preparatory work. International, governmental and non-governmental organizations liaising with the IEC also participate in this preparation. IEC collaborates closely with the International Organization for Standardization (ISO) in accordance with conditions determined by agreement between the two organizations.
- 2) The formal decisions or agreements of IEC on technical matters express, as nearly as possible, an international consensus of opinion on the relevant subjects since each technical committee has representation from all interested IEC National Committees.
- 3) IEC Publications have the form of recommendations for international use and are accepted by IEC National Committees in that sense. While all reasonable efforts are made to ensure that the technical content of IEC Publications is accurate, IEC cannot be held responsible for the way in which they are used or for any misinterpretation by any end user.
- 4) In order to promote international uniformity. IEC National Committees undertake to apply IEC Publications transparently to the maximum extent possible in their national and regional publications. Any divergence between any IEC Publication and the corresponding national or regional publication shall be clearly indicated in the latter.
- 5) IEC itself does not provide any attestation of conformity. Independent certification bodies provide conformity assessment services and in some areas, access to IEC marks of conformity. IEC is not responsible for any services carried out by independent certification bodies 62607-6-19-2021
- 6) All users should ensure that they have the latest edition of this publication.
- 7) No liability shall attach to IEC or its directors, employees, servants or agents including individual experts and members of its technical committees and IEC National Committees for any personal injury, property damage or other damage of any nature whatsoever, whether direct or indirect, or for costs (including legal fees) and expenses arising out of the publication, use of, or reliance upon, this IEC Publication or any other IEC Publications.
- 8) Attention is drawn to the Normative references cited in this publication. Use of the referenced publications is indispensable for the correct application of this publication.
- 9) Attention is drawn to the possibility that some of the elements of this IEC Publication may be the subject of patent rights. IEC shall not be held responsible for identifying any or all such patent rights.

IEC 62607-6-19 has been prepared by IEC technical committee 113: Nanotechnology for electrotechnical products and systems. It is a Technical Specification.

The text of this Technical Specification is based on the following documents:

Draft	Report on voting
113/557/DTS	113/599/RVDTS

Full information on the voting for its approval can be found in the report on voting indicated in the above table.

The language used for the development of this Technical Specification is English.

This document was drafted in accordance with ISO/IEC Directives, Part 2, and developed in accordance with ISO/IEC Directives, Part 1 and ISO/IEC Directives, IEC Supplement, available at <a href="https://www.iec.ch/members\_experts/refdocs">www.iec.ch/members\_experts/refdocs</a>. The main document types developed by IEC are described in greater detail at <a href="https://www.iec.ch/standardsdev/publications">www.iec.ch/standardsdev/publications</a>.

A list of all parts of the IEC TS 62607 series, published under the general title Nanomanufacturing – Key control characteristics, can be found on the IEC website.

The committee has decided that the contents of this document will remain unchanged until the stability date indicated on the IEC website under "http://webstore.iec.ch" in the data related to the specific document. At this date, the document will be

- reconfirmed,
- withdrawn,
- replaced by a revised edition, or
- amended.

IMPORTANT – The "colour inside" logo on the cover page of this document indicates that it contains colours which are considered to be useful for the correct understanding of its contents. Users should therefore print this document using a colour printer.

# iTeh STANDARD PREVIEW (standards.iteh.ai)

<u>IEC TS 62607-6-19:2021</u> https://standards.iteh.ai/catalog/standards/sist/2b0e1a7f-e389-4fea-9722-4cd8e4f6f681/iec-ts-62607-6-19-2021

#### INTRODUCTION

In recent decades, graphene has attracted extensive attention from academy and industry, because of its extraordinary physical and chemical properties for promising applications in energy storage, electronics, composites, etc. For most graphene powder available either in the laboratory or on the market, apart from carbon, the presence of other elements (e.g. sulfur, oxygen, nitrogen, hydrogen) is inevitable in the course of graphene fabrication. Heteroatoms in graphene can change the material's energy band at different levels, thus affecting its electrical properties and thermal conductivity [1],[2]<sup>1</sup>. Therefore, the heteroatom content is a key control characteristic which helps to ascertain the structure and purity of graphene powder, and its determination is significant for the production and application of graphene.

A method used to determine the elemental composition in graphene is the combustion/pyrolysis method, which infers the elemental composition in a sample by analysing the content of the combustion or pyrolysis gases. This method has high analysis efficiency and convenience of operation, but different instruments will provide different levels of measurement uncertainty.

In general, the combustion/pyrolysis method is established on an organic elemental analyser (EA), which uses a thermal conductivity detector (TCD) to analyse the components of the combustion or pyrolysis gases. But for graphene powder, EA is not an excellent tool to access the heteroatom content. One reason for this is that graphene has low density and sputtering happens during combustion. Another reason is that the pyrolysis temperature in EA is set at a relatively low value (e.g. 1 150 °C), which is sufficient for organics but not high enough to completely release oxygen or other atoms in graphene.

The use of a carbon/sulfur analyser (CS analyser) and an oxygen/nitrogen/hydrogen analyser (ONH analyser) can circumvent the above-mentioned problems and provide an efficient and well repeatable method for determining heteroatom content in graphene [3]. The CS analyser quantitatively analyses the combustion gas components using the infrared gas detector (IGD), while the ONH analyser quantitatively analyses the pyrolysis gas components using the TCD and IGD. The instrument has a higher pyrolysis temperature and the measurement of target gases is also completely different: hai/catalog/standards/sist/2b0e1a7f-e389-4fea-9722-4cd8e4f6f681/iec-ts-62607-6-19-2021

This document focuses on the determination of chemical composition in graphene powder and standardization of the procedures.

Numbers in square brackets refer to the Bibliography.

#### NANOMANUFACTURING - KEY CONTROL CHARACTERISTICS -

# Part 6-19: Graphene-based material – Elemental composition: CS analyser, ONH analyser

#### 1 Scope

This part of IEC TS 62607 establishes a standardized method to determine the chemical key control characteristic

elemental composition

for powder consisting of graphene-based material by

• CS analyser and ONH analyser.

The method as described in this document determines the content of carbon (C), sulfur (S), oxygen (O), nitrogen (N) and hydrogen (H).

The carbon (C) and sulfur (S) content in graphene powder is derived by the content of converted CO,  $CO_2$  and  $SO_2$ , which is determined by infrared gas detector (IGD) using a non-dispersive infrared adsorption method in CS analyser.

The content of oxygen (O), nitrogen (N) and hydrogen (H) in graphene powder is derived by ONH analyser using pyrolysis method. The O content is obtained according to the content of converted CO and  $CO_2$ , which is determined by IGD using a non-dispersive infrared adsorption method. The N content is obtained according to the content of converted  $N_2$ , which is determined by a thermal conductivity detector (TCD) method. The H content is obtained by measuring converted  $N_2$ , icorresponding to TCD or IGD3 method  $N_2$ .

• The method is applicable for graphene, graphene oxide (GO) and reduced graphene oxide (rGO) in powder form.

#### 2 Normative references

There are no normative references in this document.

#### 3 Terms and definitions

For the purposes of this document, the following terms and definitions apply.

ISO and IEC maintain terminological databases for use in standardization at the following addresses:

- IEC Electropedia: available at http://www.electropedia.org/
- ISO Online browsing platform: available at http://www.iso.org/obp

#### 3.1 General terms

#### 3.1.1

#### two-dimensional material

#### 2D material

material, consisting of one or several layers with the atoms in each layer strongly bonded to neighbouring atoms in the same layer, which has one dimension, its thickness, in the nanoscale or smaller and the other two dimensions generally at larger scales

Note 1 to entry: The number of layers when a two-dimensional material becomes a bulk material varies depending on both the material being measured and its properties. In the case of graphene layers, it is a two-dimensional material up to 10 layers thick for electrical measurements, beyond which the electrical properties of the material are not distinct from those for the bulk [also known as graphite].

Note 2 to entry: Interlayer bonding is distinct from and weaker than intralayer bonding.

- 8 -

Note 3 to entry: Each layer may contain more than one element. Note 4 to entry: A two-dimensional material can be a nanoplate.

[SOURCE: ISO/TS 80004-13:2017, 3.1.1.1]

#### 3.1.2

graphene graphene layer single-layer graphene monolayer graphene

single layer of carbon atoms with each atom bound to three neighbours in a honeycomb structure

Note 1 to entry: It is an important building block of many carbon nano-objects.

Note 2 to entry: As graphene is a single layer, it is also sometimes called monolayer graphene or single-layer graphene and abbreviated as 1LG to distinguish it from bilayer graphene (2LG) and few-layer graphene (FLG).

Note 3 to entry: Graphene has edges and can have defects and grain boundaries where the bonding is disrupted.

[SOURCE: ISO/TS 80004-13:2017, 3.1.2.1]

#### 3 1 3

#### graphene-based material

#### **GBM**

#### graphene material

grouping of carbon-based 2D materials that include one or more of graphene, bilayer graphene. few-layer graphene, graphene nanoplate, and functionalized variations thereof as well as graphene oxide and reduced graphene oxide RD PRE

Note 1 to entry: "Graphene material" is a short name for graphene-based material. (standards.iteh.ai)

#### 3.1.4

#### graphene oxide

GO

#### IEC TS 62607-6-19:2021

chemically modified mgraphenes prepared by noxidation 0 and exfoliation 2 of graphite, causing extensive oxidative modification 4 of the basal plane 07-6-19-2021

Note 1 to entry: Graphene oxide is a single-layer material with a high oxygen content, typically characterized by C/O atomic ratios of approximately 2,0 depending on the method of synthesis.

[SOURCE: ISO/TS 80004-13:2017, 3.1.2.13]

#### 3.1.5

#### reduced graphene oxide

#### rGO

reduced oxygen content form of graphene oxide

Note 1 to entry: This can be produced by chemical, thermal, microwave, photo-chemical, photo-thermal or microbial/bacterial methods or by exfoliating reduced graphite oxide.

Note 2 to entry: If graphene oxide was fully reduced, then graphene would be the product. However, in practice, some oxygen containing functional groups will remain and not all sp<sup>3</sup> bonds will return back to sp<sup>2</sup> configuration. Different reducing agents will lead to different carbon to oxygen ratios and different chemical compositions in reduced graphene oxide.

Note 3 to entry: It can take the form of several morphological variations such as platelets and worm-like structures.

[SOURCE: ISO/TS 80004-13:2017, 3.1.2.14]

#### 3.1.6

#### blank detail specification

#### **BDS**

structured generic specification of the set of key control characteristics which are needed to describe a specific nano-enabled product without assigning specific values and/or attributes

Note 1 to entry: The templates defined in a blank detail specification list the key control characteristics for the nanoenabled material or product without assigning specific values to it.

Note 2 to entry: Examples of nano-enabled products are: nanomaterials, nanocomposites and nano-subassemblies.

Note 3 to entry: Blank detail specifications are intended to be used by industrial users to prepare their detail specifications used in bilateral procurement contracts. A blank detail specification facilitates the comparison and benchmarking of different materials. Furthermore, a standardized format makes procurement more efficient and more error robust.

#### 3.1.7

### sectional blank detail specification

specification based on a blank detail specification adapted for a subgroup of the nano-enabled product

Note 1 to entry: In general the sectional blank detail specification contains a subset of those key control characteristics (KCCs) listed in the blank detail specification. In addition, sectional specific KCCs may be added if they are not listed in the blank detail specification.

Note 2 to entry: The templates defined in the sectional blank detail specification may contain KCCs with and without assigned values and attributes.

Note 3 to entry: The section can be defined by application, manufacturing method or general material properties.

#### 3.1.8

#### detail specification

DS

specification based on a blank detail specification with assigned values and attributes

Note 1 to entry: The properties listed in the detail specification are usually a subset of the key control characteristics listed in the relevant blank detail specification. The industrial partners define only those properties which are required for the intended application.

Note 2 to entry: Detail specifications are defined by the industrial partners. Standards Development Organizations will be involved only if there is a general need for a detail specification in an industrial sector.

Note 3 to entry: The industrial partners may define additional key control characteristics if they are not listed in the blank detail specification.

Teh STANDARD PREVIEW

#### 3.1.9

### key control characteristic KCC

(standards.iteh.ai)

key performance indicator

material property or intermediate product characteristic which can affect safety or compliance with regulations, fit function performance, quality, ireliability or subsequent processing of the final product 4cd8e4f6f81/iec-ts-62607-6-19-2021

Note 1 to entry: The measurement of a key control characteristic is described in a standardized measurement procedure with known accuracy and precision.

Note 2 to entry: It is possible to define more than one measurement method for a key control characteristic if the correlation of the results is well-defined and known.

#### 3.2 Key control characteristics measured according to this document

#### 3.2.1

#### carbon content

<2D material> amount of total carbon in the 2D material

#### 3.2.2

#### sulfur content

<2D material> amount of total sulfur in the 2D material

#### 3.2.3

#### oxygen content

<2D material> amount of total oxygen in the 2D material

[SOURCE: ISO/TS 80004-13:2017, 3.4.2.7]

#### 3.2.4

#### nitrogen content

<2D material> amount of total nitrogen in the 2D material

#### 3.2.5

#### hydrogen content

<2D material> amount of total hydrogen in the 2D material